



## RN1105MFV,L3F Information

Part Number RN1105MFV,L3F

Manufacturer Toshiba Semiconductor and Storage Category Discrete Semiconductor Products

Transistors - Bipolar (BJT) - Single, Pre-Biased

**Description** TRANS PREBIAS NPN 0.15W VESM

Package SOT-723

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

## **Certified Quality**

For Reference Only

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









## RN1105MFV,L3F Specifications

Manufacturer Part Number	RN1105MFV,L3F
Manufacturer	Toshiba Semiconductor and Storage
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - Single, Pre-Biased
Package	SOT-723
Series	-
Transistor Type	NPN - Pre-Biased
Current - Collector (Ic) (Max)	100mA
Voltage - Collector Emitter Breakdown (Max)	50V
Resistor - Base (R1) (Ohms)	2.2k
Resistor - Emitter Base (R2) (Ohms)	47k
DC Current Gain (hFE) (Min) @ Ic, Vce	80 @ 10mA, 5V
Vce Saturation (Max) @ Ib, Ic	300mV @ 500μA, 5mA
Current - Collector Cutoff (Max)	500nA
Frequency - Transition	-
Power - Max	150mW
Mounting Type	Surface Mount
Package / Case	SOT-723
Supplier Device Package	VESM
	Report errors?

### RN1105MFV,L3F Guarantees



### **Quality Guarantees**

We provide 90 days warranty. \*

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



#### **Service Guarantees**

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

# RN1105MFV,L3F Payment Methods



















### RN1105MFV,L3F Shipping Methods













If you have any question about RN1105MFV,L3F, please do not hesitate to contact us!

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